FAIRCHILD

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SEMICONDUCTORIM

74F00 Quad 2-Input NAND Gate

General Description

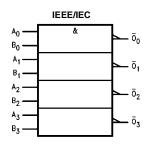
This device contains four independent gates, each of which performs the logic NAND function.

Ordering Code:

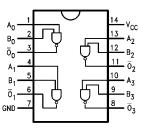
Order Number	Package Number Package Description						
74F00SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow					
74F00SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide					
74F00PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide					

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Unit Loading/Fan Out

Din Nomes	Description	U.L.	Input I _{IH} /I _{IL}		
Pin Names	Description	HIGH/LOW	Output I _{OH} /I _{OL}		
A _n , B _n	Inputs	1.0/1.0	20 µA/–0.6 mA		
Ōn	Outputs	50/33.3	–1 mA/20 mA		

Absolute Maximum Ratings(Note 1)

Storage Temperature	-65°C to +150°C
Ambient Temperature under Bias	$-55^{\circ}C$ to $+125^{\circ}C$
Junction Temperature under Bias	$-55^{\circ}C$ to $+150^{\circ}C$
V _{CC} Pin Potential to Ground Pin	-0.5V to +7.0V
Input Voltage (Note 2)	-0.5V to +7.0V
Input Current (Note 2)	-30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with $V_{CC} = 0V$)	
Standard Output	-0.5V to V _{CC}
3-STATE Output	-0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I _{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature Supply Voltage 0°C to +70°C +4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Тур	Max	Units	v _{cc}	Conditions	
V _{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal	
V _{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal	
V _{CD}	Input Clamp Diode Volta	ge			-1.2	V	Min	I _{IN} = -18 mA	
V _{OH}	Output HIGH	10% V _{CC}	2.5			V	Min	I _{OH} = -1 mA	
	Voltage	5% V _{CC}	2.7					$I_{OH} = -1 \text{ mA}$	
V _{OL}	Output LOW	10% V _{CC}			0.5	v	Min Iou = 20 mA	I _{OL} = 20 mA	
	Voltage				0.5	v	IVIIII	10L - 20 IIIA	
IIH	Input HIGH				5.0	μA	Max	V _{IN} = 2.7V	
	Current				5.0	μΑ	IVIAX	VIN - 2.7 V	
I _{BVI}	Input HIGH Current				7.0	μA	Max	V _{IN} = 7.0V	
	Breakdown Test				7.0	μΑ	IVIAX	VIN - 7.0V	
I _{CEX}	Output HIGH				50	μA	Max	V	
	Leakage Current				50	μΑ	IVIAX	V _{OUT} = V _{CC}	
V _{ID}	Input Leakage		4.75		V	v	0.0	I _{ID} = 1.9 μA	
	Test		4.75			v	0.0	All other pins grounded	
I _{OD}	Output Leakage	utput Leakage			3.75	μA	μΑ 0.0	V _{IOD} = 150 mV	
05	Circuit Current				0.70	μη υ	0.0	All other pins grounded	
IL	Input LOW Current				-0.6	mA	Max	$V_{IN} = 0.5V$	
I _{OS}	Output Short-Circuit Curr	rent	-60		-150	mA	Max	V _{OUT} = 0V	
I _{CCH}	Power Supply Current			1.9	2.8	mA	Max	V _O = HIGH	
I _{CCL}	Power Supply Current			6.8	10.2	mA	Max	V _O = LOW	

AC Electrical Characteristics

Symbol	Parameter	$T_A = +25^{\circ}C$ $V_{CC} = +5.0V$ $C_L = 50 \text{ pF}$			$T_A = -55^{\circ}C \text{ to } +125^{\circ}C$ $V_{CC} = +5.0V$ $C_L = 50 \text{ pF}$		$T_{A} = 0^{\circ}C \text{ to } +70^{\circ}C$ $V_{CC} = +5.0V$ $C_{L} = 50 \text{ pF}$		Units
		Min	Тур	Max	Min	Max	Min	Max	
t _{PLH}	Propagation Delay	2.4	3.7	5.0	2.0	7.0	2.4	6.0	
PLN	r ropagation Delay	2.7	0.7	0.0	2.0	1.0	2.4	0.0	ns

